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| APPLICATION NO.                           | FILING DATE | FIRST NAMED INVENTOR   | ATTORNEY DOCKET NO.     | CONFIRMATION NO |
|---|-------------|--|-------------------------|-----------------|
| 10/751,443                                | 01/06/2004  | Hongmei Wang   | M4065.0536/P536-B       | 2565            |
| 24998                                     | 7590 03/16/ | 2006   | EXAM                    | INER            |
|   | SHAPIRO MOI | PIZARRO CRESPO, MARCOS D   |                         |                 |
| 2101 L Street, NW<br>Washington, DC 20037 |             |  | ART UNIT                | PAPER NUMBER    |
|   |             | OIPE   | 2814                    |                 |
|   |             |  | DATE MAILED: 03/16/2006 |                 |
|   |             | MAR 2 2 2006   |                         |                 |
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Please find below and/or attached an Office communication concerning this application or proceeding.

| 4  | Application No.   | Applicant(s)  |  |  |  |  |
|--|---|---|--|--|--|--|
|  | 10/751,443  | WANG ET AL.   |  |  |  |  |
| Office Action Summary  | Examiner  | Art Unit  |  |  |  |  |
|  | Marcos D. Pizarro-Crespo  | 2814  |  |  |  |  |
| The MAILING DATE of this communication appears on the cover sheet with the correspondence address Period for Reply   |   |   |  |  |  |  |
| A SHORTENED STATUTORY PERIOD FOR REPLY WHICHEVER IS LONGER, FROM THE MAILING DA  - Extensions of time may be available under the provisions of 37 CFR 1.13 after SIX (6) MONTHS from the mailing date of this communication.  - If NO period for reply is specified above, the maximum statutory period w  - Failure to reply within the set or extended period for reply will, by statute, Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).   | ATE OF THIS COMMUNICATION 36(a). In no event, however, may a reply be tim will apply and will expire SIX (6) MONTHS from a cause the application to become ABANDONE | N.<br>nely filed<br>the mailing date of this communication.<br>D (35 U.S.C. § 133). |  |  |  |  |
| Status   |   |   |  |  |  |  |
| <ol> <li>Responsive to communication(s) filed on 12 December 2a) This action is FINAL.</li> <li>Since this application is in condition for alloware closed in accordance with the practice under Exercise.</li> </ol>  | action is non-final.<br>nce except for formal matters, pro  |   |  |  |  |  |
|  |   |   |  |  |  |  |
| Disposition of Claims  |   |   |  |  |  |  |
| 4) ☐ Claim(s) 27 and 32-35 is/are pending in the ap 4a) Of the above claim(s) is/are withdray 5) ☐ Claim(s) is/are allowed. 6) ☐ Claim(s) 27 and 32-35 is/are rejected. 7) ☐ Claim(s) is/are objected to. 8) ☐ Claim(s) are subject to restriction and/o   | wn from consideration.  |   |  |  |  |  |
| Application Papers   |   |   |  |  |  |  |
| 9) ☐ The specification is objected to by the Examine 10) ☑ The drawing(s) filed on <u>06 January 2004</u> is/are: Applicant may not request that any objection to the Replacement drawing sheet(s) including the correct 11) ☐ The oath or declaration is objected to by the Ex  | : a) ☐ accepted or b) ☒ objected or b) ☒ objected or b) ☒ objected or awing(s) be held in abeyance. Section is required if the drawing(s) is objected.              | e 37 CFR 1.85(a).<br>jected to. See 37 CFR 1.121(d).                                |  |  |  |  |
| Priority under 35 U.S.C. § 119   |   |   |  |  |  |  |
| <ul> <li>12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).</li> <li>a) All b) Some * c) None of:</li> <li>1. Certified copies of the priority documents have been received.</li> <li>2. Certified copies of the priority documents have been received in Application No.</li> <li>3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).</li> <li>* See the attached detailed Office action for a list of the certified copies not received.</li> </ul> |   |   |  |  |  |  |
| Attachment(s)  1) Notice of References Cited (PTO-892)  2) Notice of Draftsperson's Patent Drawing Review (PTO-948)  | 4) Interview Summary Paper No(s)/Mail Di  |   |  |  |  |  |
| 3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date   | 6) Other:   | atent Application (FTO-192)   |  |  |  |  |

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Attorney's Docket Number: M4065.0536/P536-B

Filing Date: 1/6/2004

Claimed Priority Dates: 11/26/2002 (Continuation of 10/303,696)

6/5/2002 (Divisional of 10/161,615)

Applicant(s): Wang, et al.

Examiner: Marcos D. Pizarro-Crespo

#### **DETAILED ACTION**

This Office action responds to the amendment and declaration filed on 12/12/2005.

### Acknowledgment

1. The amendment and declaration filed on 5/19/2005, responding to the Office action mailed on 6/10/2005, has been entered. The present Office action is made with all the suggested amendments being fully considered. Accordingly, pending in this Office action are claims 27 and 32-35.

## **Drawings**

- 2. The drawings are objected to as failing to comply with 37 CFR 1.84(p)(5) because they do not include the following reference sign(s) mentioned in the description (see, e.g., par.0041/II.6) with respect to figure 19: **100**.
- 3. Corrected drawing sheets in compliance with 37 CFR 1.121(d) are required in reply to the Office action to avoid abandonment of the application. Any amended replacement-drawing sheet should include all of the figures appearing on the immediate prior version of the sheet, even if only one figure is being amended. The figure or figure number of an amended drawing should not be labeled as "amended." If a drawing figure is to be canceled, the appropriate figure must be removed from the replacement sheet,

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and where necessary, the remaining figures must be renumbered and appropriate changes made to the brief description of the several views of the drawings for consistency. Additional replacement sheets may be necessary to show the renumbering of the remaining figures. Each drawing sheet submitted after the filing date of an application must be labeled in the top margin as either "Replacement Sheet" or "New Sheet" pursuant to 37 CFR 1.121(d). If the examiner does not accept the changes, the applicant will be notified and informed of any required corrective action in the next Office action. The objection to the drawings will not be held in abeyance.

## Claim Rejections - 35 USC § 103

- 4. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
  - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 5. This application currently names joint inventors. In considering patentability of the claims under 35 U.S.C. 103(a), the examiner presumes that the subject matter of the various claims was commonly owned at the time any inventions covered therein were made absent any evidence to the contrary.
- 6. Applicant is advised of the obligation under 37 CFR 1.56 to point out the inventor and invention dates of each claim that was not commonly owned at the time a later invention was made in order for the examiner to consider the applicability of 35 U.S.C. 103(c) and potential 35 U.S.C. 102(e), (f) or (g) prior art under 35 U.S.C. 103(a).

- 7. Claims 27, 32, and 33 are rejected under 35 U.S.C. 103(a) as being unpatentable over Yu (US 6484065) in view of Houston (US 6424016) and King (US 6754104).
- 8. Regarding claim 27, Yu (see, e.g., fig. 1) shows most aspects of the instant invention including a processor-based system **100** comprising
  - > A processor 110
- ➤ An integrated circuit **120** coupled to the processor **110**wherein the circuit comprises a transistor, the transistor comprising source/drain regions of a first conductivity type and a gate stack including a conductive layer.

Although not explicit, Yu shows the circuit including DRAM banks **120a-d**, which by definition are made of transistors, each with its respective first-conductivity-type source/drain regions and conductive-layer gate stack.

Yu, however, fails to specify that the source/drain regions and the gate stack be provided on an SOI substrate and that the conductive layer of the gate stack is of a second conductivity type.

Houston (see, e.g., col.1/II.14-25), on the other hand, teaches that SOI substrates are good for DRAMs for several reasons. One reason is that SOIs have lower collection volumes.

Like Yu, Houston (see, e.g., figs. 5-6 and col.4/II.54-58) also shows DRAMs including transistors having source/drain regions of a first conductivity type (n-type) and a gate stack **40** including a conductive layer of a second conductivity type (p-type).

These are fully depleted SOI NMOS 40 41 forming part of a memory array (see, e.g., col.5/II.52-53).

Houston also shows a partially depleted SOI NMOS transistor 42 comprising source/drain regions provided on the substrate. The source/drain regions are of n-type conductivity (see, e.g., col.5/II.54-56 and col.6/II.7-9). A second gate stack is fabricated on the substrate including a conductive layer of a p-type conductivity (see, e.g., col.5/II.50-51).

It would have been obvious at the time of the invention to one of ordinary skill in the art to have Yu's integrated circuit comprising fully-depleted and partially-depleted transistors having gate stacks and source/drain regions provided on an SOI substrate, wherein the gate stacks are p-type and the source/drain regions are n-type, as suggested by Houston, to lower the collection volume of the integrated circuit.

Yu/Houston teach using polysilicon as the gate material (see, e.g., Houston/col.5/II.50-60) but fail to teach using silicon/germanium. King, on the other hand, teaches (see, e.g., col.15/II.20-30) that polysilicon and silicon/germanium are equivalents for their use as gate materials.

Therefore, because polysilicon and silicon/germanium were recognized in the art at the time of the invention as equivalents for their use as gate materials, one of ordinary skill in the art would have found it obvious to substitute Yu/Houston's doped polysilicon for the silicon/germanium that King suggested.

Regarding claim 32, Houston shows that the conductive layer of the gate stack is 9. a doped polysilicon layer (see, e.g., col.5/II.50).

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- 10. Regarding claim 33, King teaches that the conductive layer is silicon/germanium (see, e.g., col/15/II.20-30).
- 11. Claims 34 and 35 are rejected under 35 U.S.C. 103(a) as being unpatentable over Yu/Houston/King in view of Wu (US 6060749).
- 12. Regarding claims 34 and 35, Yu/Houston/King show most aspects of the instant invention (see, e.g., paragraph 8 above), except for at least one of the gate stacks further comprising a silicide layer or a cap layer over the conductive layer.

Wu (see, e.g., col.5/II.9-18), on the other hand, teaches that having a silicide cap layer over Yu/Houston/King's gate will reduce the parasitic resistance of the gate.

It would have been obvious at the time of the invention to one of ordinary skill in the art to form a silicide cap layer over Yu/Houston/King's conductive layer, as suggested by Wu, to reduce the parasitic resistance of the gate.

### Response to Declaration

13. The declaration filed on 12/12/2005 under 37 CFR 1.131 is sufficient to overcome the Krivokapic reference (US 6452229).

### Response to Arguments

14. Applicant's arguments with respect to the claims have been considered but are most in view of the new ground(s) of rejection.

#### Conclusion

15. Papers related to this application may be submitted directly to Art Unit 2814 by facsimile transmission. Papers should be faxed to Art Unit 2814 via the Art Unit 2814 Fax Center. The faxing of such papers must conform to the notice published in the

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Official Gazette, 1096 OG 30 (15 November 1989). The Art Unit 2814 Fax Center number is (571) 273-8300. The Art Unit 2814 Fax Center is to be used only for papers related to Art Unit 2814 applications.

- 16. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Marcos D. Pizarro-Crespo at (571) 272-1716 and between the hours of 9:30 AM to 8:00 PM (Eastern Standard Time) Monday through Thursday or by e-mail via <a href="Marcos.Pizarro@uspto.gov">Marcos.Pizarro@uspto.gov</a>. If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Wael Fahmy, can be reached on (571) 272-1705.
- 17. Any inquiry of a general nature or relating to the status of this application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

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# 18. The following list is the Examiner's field of search for the present Office Action:

| Field of Search                                | Date      |
|--|-----------|
| U.S. Class / Subclass(es): 257/347-354,407     | 1/23/2006 |
| Other Documentation: PLUS Analysis             | 3/15/2005 |
| Electronic Database(s): EAST (USPAT, EPO, JPO) | 1/23/2006 |

Marcos D. Pizarro-Crespo

Patent Examiner Art Unit 2814 571-272-1716

marcos.pizarro@uspto.gov

MDP/mdp February 28, 2006

#### Application/Control No. Applicant(s)/Patent Under Reexamination 10/751,443 WANG ET AL. Notice of References Cited Art Unit Examiner Page 1 of 1 2814 Marcos D. Pizarro-Crespo **U.S. PATENT DOCUMENTS** Document Number Date Name Classification Country Code-Number-Kind Code MM-YYYY US-6,754,104 06-2004 365/185.14 King, Tsu-Jae Α US-В US-С US-D US-Ε US-F US-G US-Н US-US-J US-K US-L М US-FOREIGN PATENT DOCUMENTS **Document Number** Date Country Name Classification Country Code-Number-Kind Code MM-YYYY Ν 0 Ρ Q R s Т **NON-PATENT DOCUMENTS** Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages) U ٧ W

"A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).) Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.

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